

# CPD85V-CMPSH1-4L Schottky Rectifier Die 1.0 Amp, 40 Volt

The CPD85V-CMPSH1-4L is an ultra low  $V_{\mbox{F}}$  silicon Schottky rectifier designed for applications where operational efficiency is a prime requirement.

		MECHANICA	L SPECIFICAT	IONS:		
		Die Size		39.4 x 39.4 MILS		
		Die Thickness		7.1 MILS		
		Anode Bonding Pad Size		35 x 35 MILS		
Back Scribe Wafe		Top Side Metalization		AI – 30,000Å		
		Back Side Metalization		Au – 9,000Å		
		Scribe Alley Width		1.97 MILS		
		Wafer Diameter		5 INCHES		
		Gross Die Pe	Gross Die Per Wafer		10,900	
BACK	SIDE CATHODE R0					
MAXIMUM RATINGS: (T <sub>A</sub> =25°C) Continuous Reverse Voltage			SYMBOL V <sub>R</sub>	40		UNITS V
Average Forward Current			lo	1.0		А
Peak Forward Surge Current, tp=8.3ms			IFSM	2	20	
Operating and Storage Junction Temperature			т <sub>Ј</sub> , т <sub>stg</sub>	-65 to +150		°C
ELECTRIC	AL CHARACTERISTIC	<b>:</b> (T <sub>A</sub> =25°C ເ	unless otherwise	e noted)		
symbol I <sub>R</sub>	TEST CONDITION	S	MIN	TYP	<b>MAX</b> 900	<b>UNITS</b> μΑ
I <sub>R</sub>	V <sub>R</sub> =30V				1.5	mA
BVR	I <sub>R</sub> =1.0mA		40			V
VF	I <sub>F</sub> =100mA				270	mV
VF	I <sub>F</sub> =500mA				340	mV
V <sub>F</sub>	I <sub>F</sub> =1.0A				390	mV
VF	I <sub>F</sub> =1.5A				420	mV
Сј	V <sub>R</sub> =10V, f=1.0MHz	1		50		pF

### MECHANICAL SPECIFICATIONS:

R0 (23-January 2017)

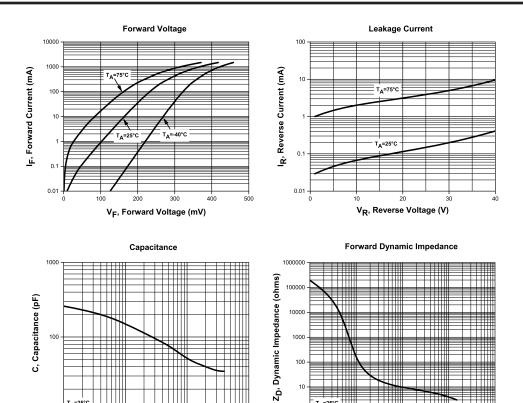
# CPD85V-CMPSH1-4L **Typical Electrical Characteristics**

T<sub>A</sub>=25°C

10 + 0.1

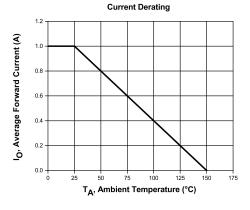


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T<sub>A</sub>=25°C 1+ I<sub>F</sub>, Forward Current (mA)

1000



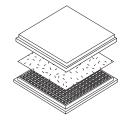
10

V<sub>R</sub>, Reverse Voltage (V)

R0 (23-January 2017)

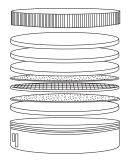
## BARE DIE PACKING OPTIONS





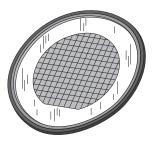
## BARE DIE IN TRAY (WAFFLE) PACK

- CT: Singulated die in tray (waffle) pack. (example: CP211-PART NUMBER-CT)
- CM: Singulated die in tray (waffle) pack 100% visually inspected as per MIL-STD-750, (method 2072 transistors, method 2073 diodes). (example: CP211-PART NUMBER-CM)



### UNSAWN WAFER

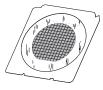
WN: Full wafer, unsawn, 100% tested with reject die inked. (example: CP211-PART NUMBER-WN)



## SAWN WAFER ON PLASTIC RING

WR: Full wafer, sawn and mounted on plastic ring, 100% tested with reject die inked. (example: CP211-PART NUMBER-WR)

Please note: Sawn Wafer on Metal Frame (WS) is possible as a special order. Please contact your Central Sales Representative at 631-435-1110.



R1 (10-February 2017)

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- Inventory bonding
- Consolidated shipping options

- Custom bar coding for shipments
- Custom product packing

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Central's applications engineering team is ready to discuss your design challenges. Just ask.

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- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

### CONTACT US

#### **Corporate Headquarters & Customer Support Team**

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